# TYPE 6B7 DUODIODE HIGH GAIN PENTODE





#### CHARACTERISTICS

								e.	
Heater Voltage A			16				6.3	Volts	
Heater Current .							0.3	Ampere	

# Direct Interelectrode Ca

Direct II	ite	rei	ec	u	Jue		ap	ac	ıta	nc	es	:			
Grid to P	late	(w	ith	tul	oe s	hiel	d)				٠.			0.007	μμί
input .														3.5	uuf
Output									-					9.5	μμί
Maximum C	ver	-all	L	engt	h.										417"
Maximum L	nan	nete	er												1 34"
Bulb															ST-12
Cap															Small Metal
Base—Small	7-1	Pin	•												7-D

## Operating Conditions and Characteristics:

#### DIODE UNITS

With an applied d-c plate voltage of 10 volts the space current per plate (no external load) should exceed 0.5 milliampere.

#### PENTODE UNIT

				CL	ASS	S A	AMI	PLIFIE	R		
Heater Voltage							6.3	6.3	6.3	6.3	Volts
Plate Voltage							100	180	250	250	Volts Max.
Screen Voltage								75	100		Volts Max.
Grid Voltage							-3	-3	-3	-3	Volts
Plate Current			-				5.8	3.4	6.0	9.0	Ma.
Screen Current							1.7	0.9	1.5	2.3	Ma.
Grid Bias Voltag	ge*						-17	-13	-17	-21	Volts
Plate Resistance	9						0.3	1.0	0.8		Megohm
Mutual Conduct	tan	ce			į.		950	840	1000		μmhos
Amplification Fa	acto	or					285	840	800	730	MILLION

\*For Cathode Current Cut-off.

#### CIRCUIT APPLICATION

The complex structure of this tube is such that it is called a "duodiode pentode." This name reveals the multi-service possibilities of the tube. It is designed for performing simultaneously the functions of detection, amplification, and automatic volume control.

The tube has a single cathode structure. The emitting surface on the sleeve is in two sections: one for the diodes and the other for the pentode unit. This permits independent operation of the two sections and extends the usefulness of the tube. A 7-pin base and top cap provide separate external connections for all the elements.

The 6B7 is applicable in automobile, AC, AC-DC, or DC sets.

The heater rating is 0.3 ampere at 6.3 volts.

Duodiode triodes have been used extensively for the combined service as detector, amplifier and automatic volume control tubes. Types 55, 75 and 85 utilize this structural arrangement. The primary difference between this group and Type 6B7 is in the primary difference between this group and Type obt is in the amplifier section. In the former group this is a triode unit, while in the latter it takes the form of a pentode.

Although the amplifier section of duodiode triodes is generally restricted in application to audio frequency stages, nevertheless,

these types are more popular than duodiode pentodes. The primary cause for this is the saving in cost. Type 6B7 is a more expensive tube to manufacture than the 75 and, therefore, the price is higher. Furthermore, when the former type is used, a resistor and voltage supply must be provided for the screen circuit. Nevertheless, special circuit design requirements may justify the increased expenditure of using a Type 6B7. Comparison of the application notes given below with those described under Circuit Application on Type 75 will prove helpful in determining which of these tubes will be superior in any given circuit.

#### Detection:

The diode section is readily adapted to detector service. A diode system is characterized by high rectifying efficiency. Furthermore, with proper choice of load resistance it is possible to main-

tain the distortion of the rectified signal at a minimum.

There being two diodes available in this tube, it is possible to use them either for independent functions (one for a.v.c. and one for detection); or they may be used in conjunction with each other, either in parallel or in a full-wave rectifier circuit. The halfwave arrangement will give nearly twice as much audio or a-v-c voltage for a given carrier as the full-wave connection, but it requires better carrier frequency filtering.
When both diodes are used separately, delayed a.v.c. may be

obtained independent of squelch action so that the maximum or

Usually the regulating voltage is applied to the control grids of the r-f or i-f amplifier, or to both. However, some circuits may permit one to secure control through the application of the regulating voltage is a secure control through the application of the regulating voltage to the closer of are in the control of the regulating voltage to the closer of are in the control through the application of the regulating voltage to the closer of are in the control of the regulating voltage to the closer of are in the control of the regulating voltage to the control of are in the control of the regulating voltage to the control of are in the control of the regulating voltage to the control of the regulation of the regulating voltage to the control of the regulation of the regulatio lating voltage to other elements of an r-f pentode.

## Amplification (R.F. or I.F.):

Conventional circuits for a pentode are applicable to the pentode section of the 6B7. The cut-off characteristics are midway between the sharp and extended types which permits moderate gain control by means of proper grid bias variation.

# Amplification (A.F.):

The pentode section may be used in a resistance coupled circuit to provide high gain. The grid bias should be obtained from a fixed voltage tap on the d-c power supply. Resistance in the grid circuit should not exceed 1.0 megohm. Suggested operating conditions for this service are:

Heater Voltage									6.3	Volts	
Plate Supply V	olta	age							250	Volts	
Screen Voltage									50	Volts	
Grid Voltage										Volts	
Plate Load .									0.2	Megohm	
Plate Current										Ma.	

Reflex operation of Type 6B7 is also possible where space is at a premium and a-v-c action is not essential. The usual method is to reflex the audio through the pentode section which is already being employed for i-f amplification. The diodes, of course, are utilized for the function of detection. For resistance coupled audio in reflexed service the following operating conditions have been found most suitable:

Heater Voltage								6.3	Volts	
Plate Supply Voltage								250	Volts	
Screen Voltage								40	Volts	
Grid Voltage								-2	Volts	
Plate Current								1.4	Ma.	
Plate Load Resistor									Megohm	
Diode Load Resistor									Megohm	
I-F Filter Resistor .								0.25	Megohm	
Grid Coupling Resisto	r							1.0	Megohm	
Diode Load By-pass							0	.0002	$\mu$ f	
Grid Resistor By-pass							0	.0001	$\mu$ f	
Plate Load By-pass							0	.0001	μf	